

Darlington Silicon

Power Transistors

... designed for general-purpose amplifier and low speed switching applications.

- High DC Current Gain — $h_{FE} = 3500$ (Typ) @ $I_C = 4$ Adc
- Collector–Emitter Sustaining Voltage — @ 200 mAdc
 - $V_{CEO(sus)} = 60$ Vdc (Min) — 2N6667
 - $= 80$ Vdc (Min) — 2N6668
- Low Collector–Emitter Saturation Voltage — $V_{CE(sat)} = 2$ Vdc (Max) @ $I_C = 5$ Adc
- Monolithic Construction with Built-In Base–Emitter Shunt Resistors
- TO–220AB Compact Package
- Complementary to 2N6387, 2N6388

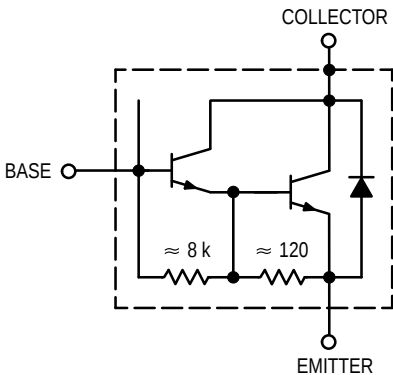


Figure 1. Darlington Schematic

2N6609

(See 2N3773)

2N6667

2N6668

PNP SILICON

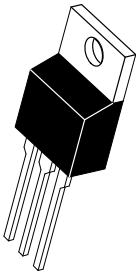
DARLINGTON

POWER TRANSISTORS

10 AMPERES

60–80 VOLTS

65 WATTS



CASE 221A–06

TO–220AB

MAXIMUM RATINGS (1)

Rating	Symbol	2N6667	2N6668	Unit
Collector–Emitter Voltage	V_{CEO}	60	80	Vdc
Collector–Base Voltage	V_{CB}	60	80	Vdc
Emitter–Base Voltage	V_{EB}	5		Vdc
Collector Current — Continuous — Peak	I_C	10 15		Adc
Base Current	I_B	250		mAdc
Total Device Dissipation @ $T_C = 25^{\circ}\text{C}$ Derate above 25°C	P_D	65 0.52		watts W/ $^{\circ}\text{C}$
Total Device Dissipation @ $T_A = 25^{\circ}\text{C}$ Derate above 25°C	P_D	2 0.016		Watts W/ $^{\circ}\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +150		$^{\circ}\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	1.92	$^{\circ}\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^{\circ}\text{C/W}$

(1) Indicates JEDEC Registered Data.



2N6667 2N6668***ELECTRICAL CHARACTERISTICS** ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (1) ($I_C = 200\text{ mAdc}$, $I_B = 0$)	2N6667 2N6668 $V_{CE(sus)}$	60 80	— —	Vdc
Collector Cutoff Current ($V_{CE} = 60\text{ Vdc}$, $I_B = 0$) ($V_{CE} = 80\text{ Vdc}$, $I_B = 0$)	2N6667 2N6668 I_{CEO}	— —	1 1	mAdc
Collector Cutoff Current ($V_{CE} = 60\text{ Vdc}$, $V_{EB(off)} = 1.5\text{ Vdc}$) ($V_{CE} = 80\text{ Vdc}$, $V_{EB(off)} = 1.5\text{ Vdc}$) ($V_{CE} = 60\text{ Vdc}$, $V_{EB(off)} = 1.5\text{ Vdc}$, $T_C = 125^\circ\text{C}$) ($V_{CE} = 80\text{ Vdc}$, $V_{EB(off)} = 1.5\text{ Vdc}$, $T_C = 125^\circ\text{C}$)	2N6667 2N6668 2N6667 2N6668 I_{CEX}	— — — —	300 300 3 3	μAdc mAdc
Emitter Cutoff Current ($V_{BE} = 5\text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	5	mAdc

ON CHARACTERISTICS (1)

DC Current Gain ($I_C = 5\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$) ($I_C = 10\text{ Adc}$, $V_{CE} = 3\text{ Vdc}$)	h_{FE}	1000 100	20000 —	—
Collector–Emitter Saturation Voltage ($I_C = 5\text{ Adc}$, $I_B = 0.01\text{ Adc}$) ($I_C = 10\text{ Adc}$, $I_B = 0.1\text{ Adc}$)	$V_{CE(sat)}$	— —	2 3	Vdc
Base–Emitter Saturation Voltage ($I_C = 5\text{ Adc}$, $I_B = 0.01\text{ Adc}$) ($I_C = 10\text{ Adc}$, $I_B = 0.1\text{ Adc}$)	$V_{BE(sat)}$	— —	2.8 4.5	Vdc

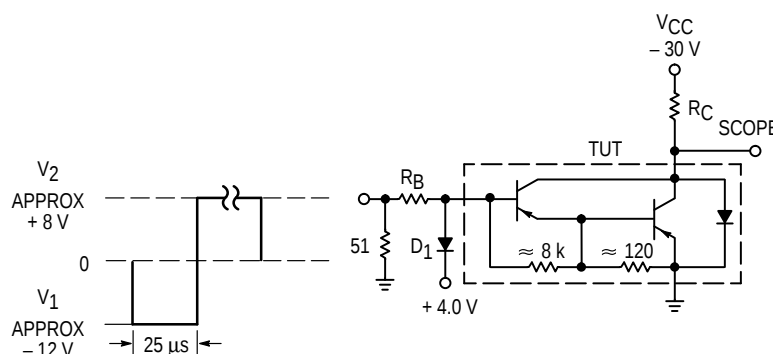
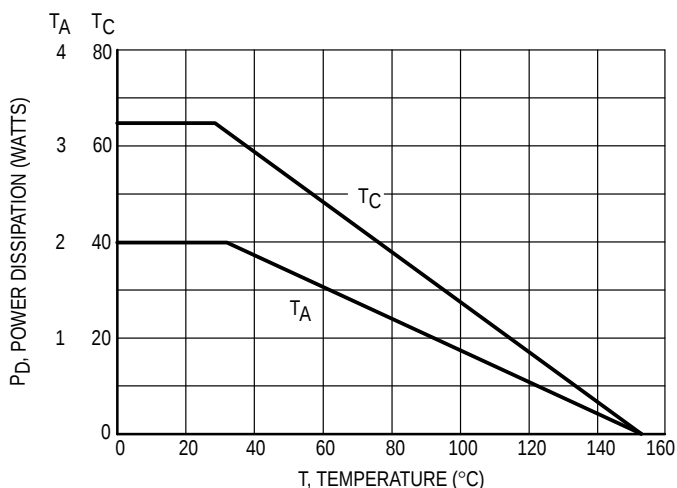
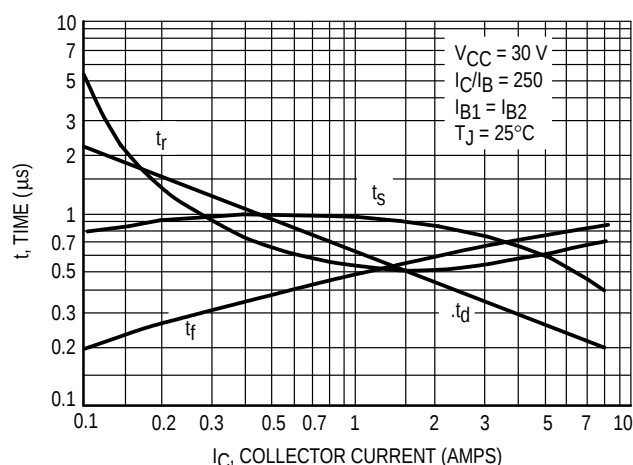
DYNAMIC CHARACTERISTICS

Current Gain — Bandwidth Product ($I_C = 1\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$, $f_{test} = 1\text{ MHz}$)	$ h_{fe} $	20	—	—
Output Capacitance ($V_{CB} = 10\text{ Vdc}$, $I_E = 0$, $f = 1\text{ MHz}$)	C_{ob}	—	200	pF
Small–Signal Current Gain ($I_C = 1\text{ Adc}$, $V_{CE} = 5\text{ Vdc}$, $f = 1\text{ kHz}$)	h_{fe}	1000	—	—

* Indicates JEDEC Registered Data

(1) Pulse Test: Pulse Width $\leq 300\text{ }\mu\text{s}$, Duty Cycle $\leq 2\%$. R_B & R_C VARIED TO OBTAIN DESIRED CURRENT LEVELS D_1 , MUST BE FAST RECOVERY TYPES e.g.,1N5825 USED ABOVE $I_B \approx 100\text{ mA}$ MSD6100 USED BELOW $I_B \approx 100\text{ mA}$ FOR t_d AND t_r , D_1 IS DISCONNECTED AND $V_2 = 0$ $t_r, t_f \leq 10\text{ ns}$

DUTY CYCLE = 1.0%

**Figure 2. Switching Times Test Circuit****Figure 3. Power Derating****Figure 4. Typical Switching Times**

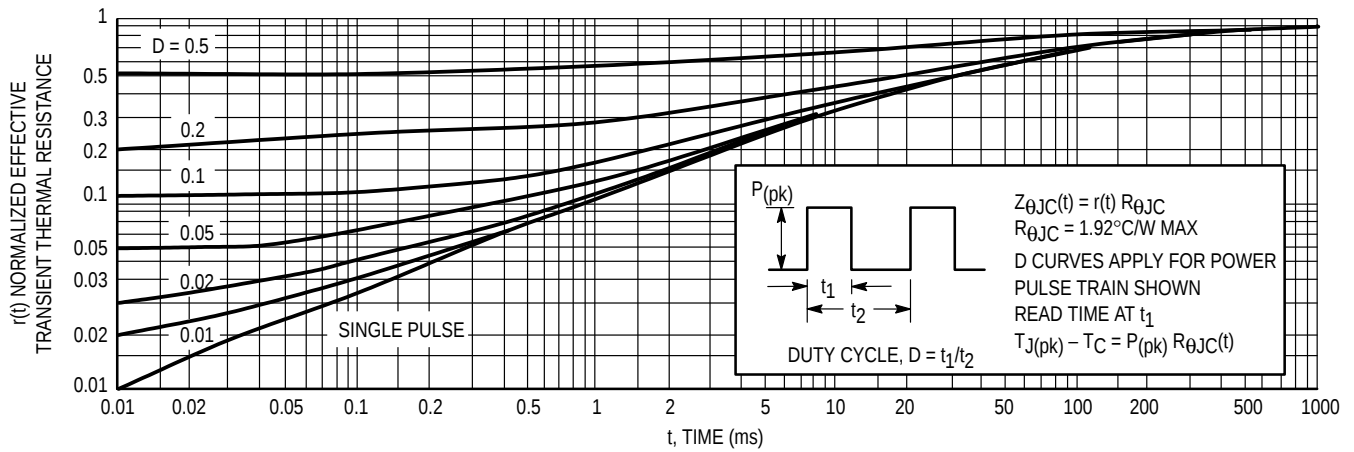


Figure 5. Thermal Response

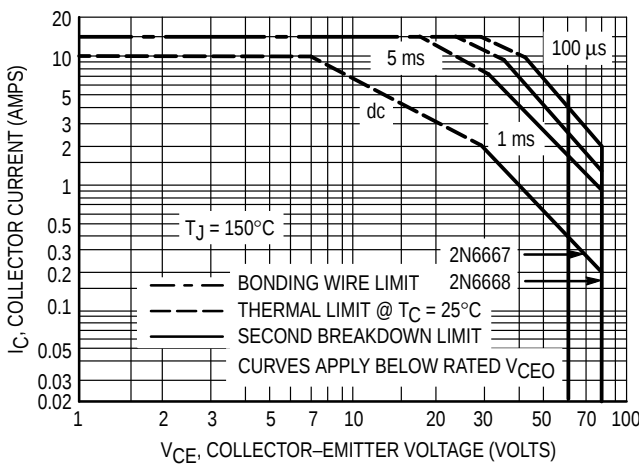


Figure 6. Maximum Safe Operating Area

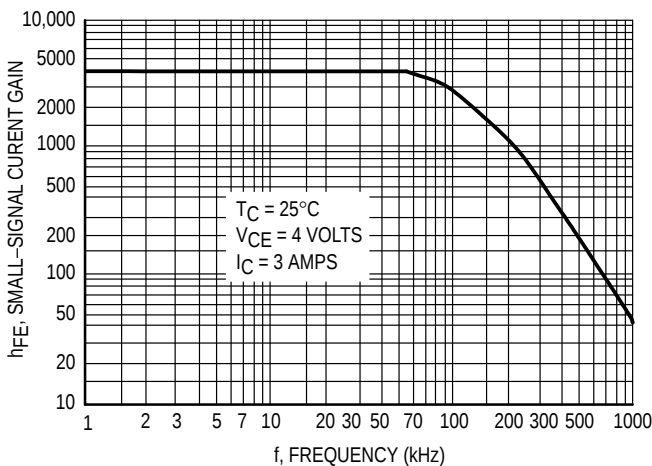


Figure 7. Typical Small-Signal Current Gain

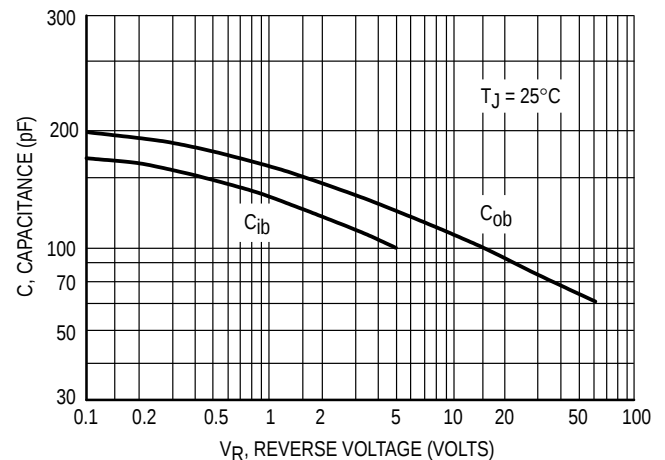
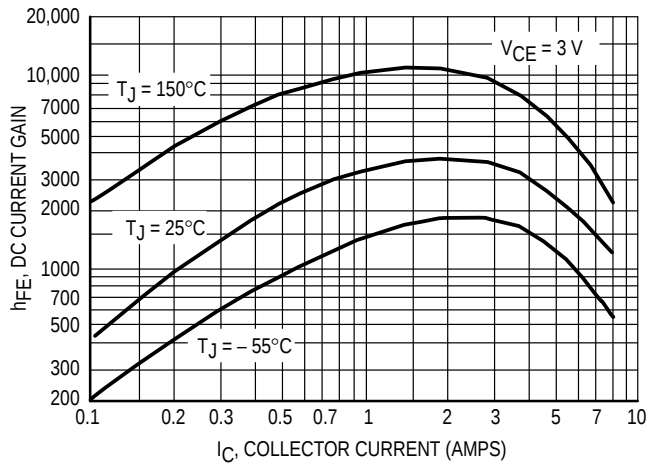
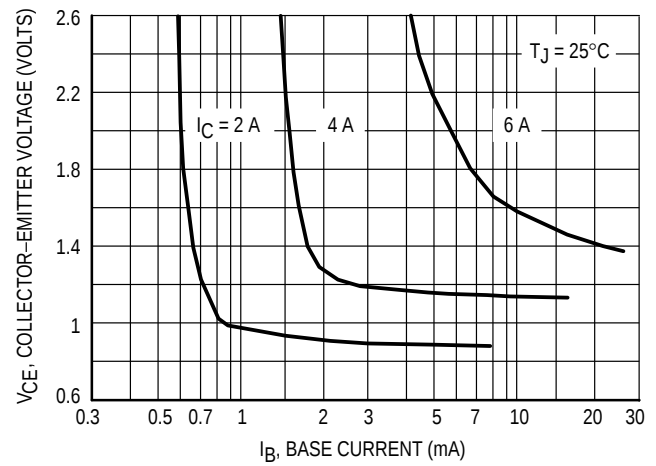
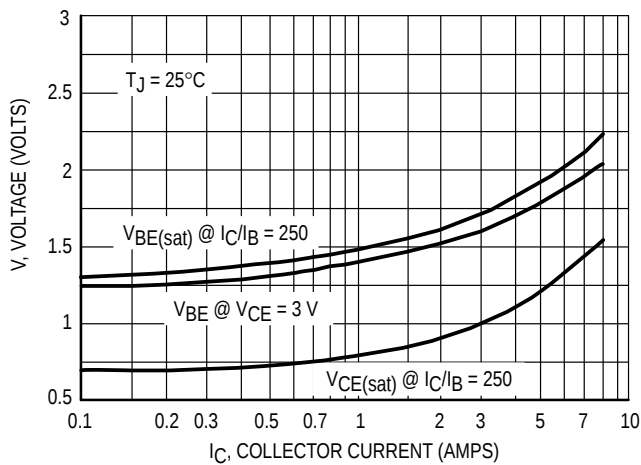
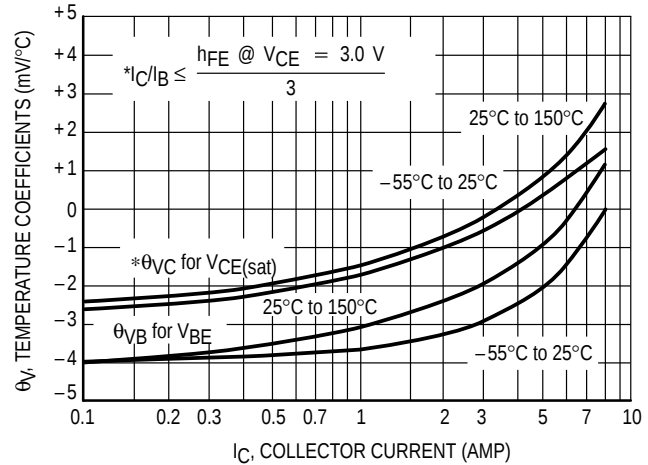
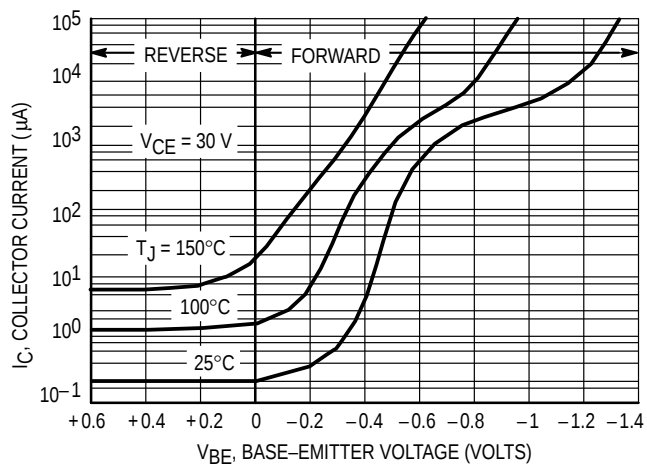
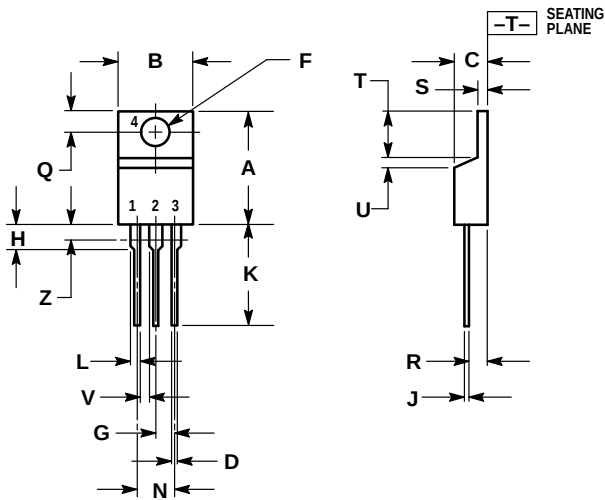


Figure 8. Typical Capacitance

2N6667 2N6668**Figure 9. Typical DC Current Gain****Figure 10. Typical Collector Saturation Region****Figure 11. Typical "On" Voltages****Figure 12. Typical Temperature Coefficients****Figure 13. Typical Collector Cut-Off Region**

2N6667 2N6668

PACKAGE DIMENSIONS



- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: INCH.
 - 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	—	1.15	—
Z	—	0.080	—	2.04

- STYLE 1:
- PIN 1. BASE
 - 2. COLLECTOR
 - 3. EMITTER
 - 4. COLLECTOR

CASE 221A-06
TO-220AB
ISSUE Y

2N6667 2N6668

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